AC6328B Datasheet

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Version：V1.3

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AC6328B Features

High performance 32-bit RISC CPU

- RISC 32-bit CPU
- DC-96MHz operation
- 73KB data RAM
- 8KB I-cache 2way
- 1KB Rocache 1way
- 64 Vectored interrupts
- 8 Levels interrupt priority

Flexible I/O

- 2 GPIO pins
- All GPIO pins can be programmable as input or output individually
- All GPIO pins are internal pull-up/pull-down selectable individually
- CMOS/TTL level schmitt triggered input
- External wake up/interrupt on all GPIOs

Peripheral Feature

- One Full Speed USB OTG controller
- One full-duplex advanced UART(DMA)
- One IIC interface supports host and device mode
- 2 channels 10-bit ADC
- 1 channel 8 levels Low Power Detector
- Embedded PMU support low power mode
- Watchdog
- Power-on reset

Bluetooth Feature

- CMOS single-chip fully-integrated radio and baseband
- Compliant with Bluetooth V5.4+BR+EDR+BLE specification
- Bluetooth Piconet and Scatternet support
- Meet class2 and class3 transmitting power requirement
- Support GFSK and π/4 DQPSK all packet types
- Maximum +8dBm transmitting power
- EDR receiver with -93dBm sensitivity
- Support a2dp\avctp\avdtp\avrcp\hfp\spp\smp\att\gap\gatt\rfcomm\sdp\l2cap profile

Power Supply

- VBAT is 1.8V to 5.5V
- VDDIO is 1.8V to 3.4V

Packages

- SOP8

Temperature

- Operating temperature: -40℃ to +85℃
- Storage temperature: -65℃ to +150℃

1.Block Diagram

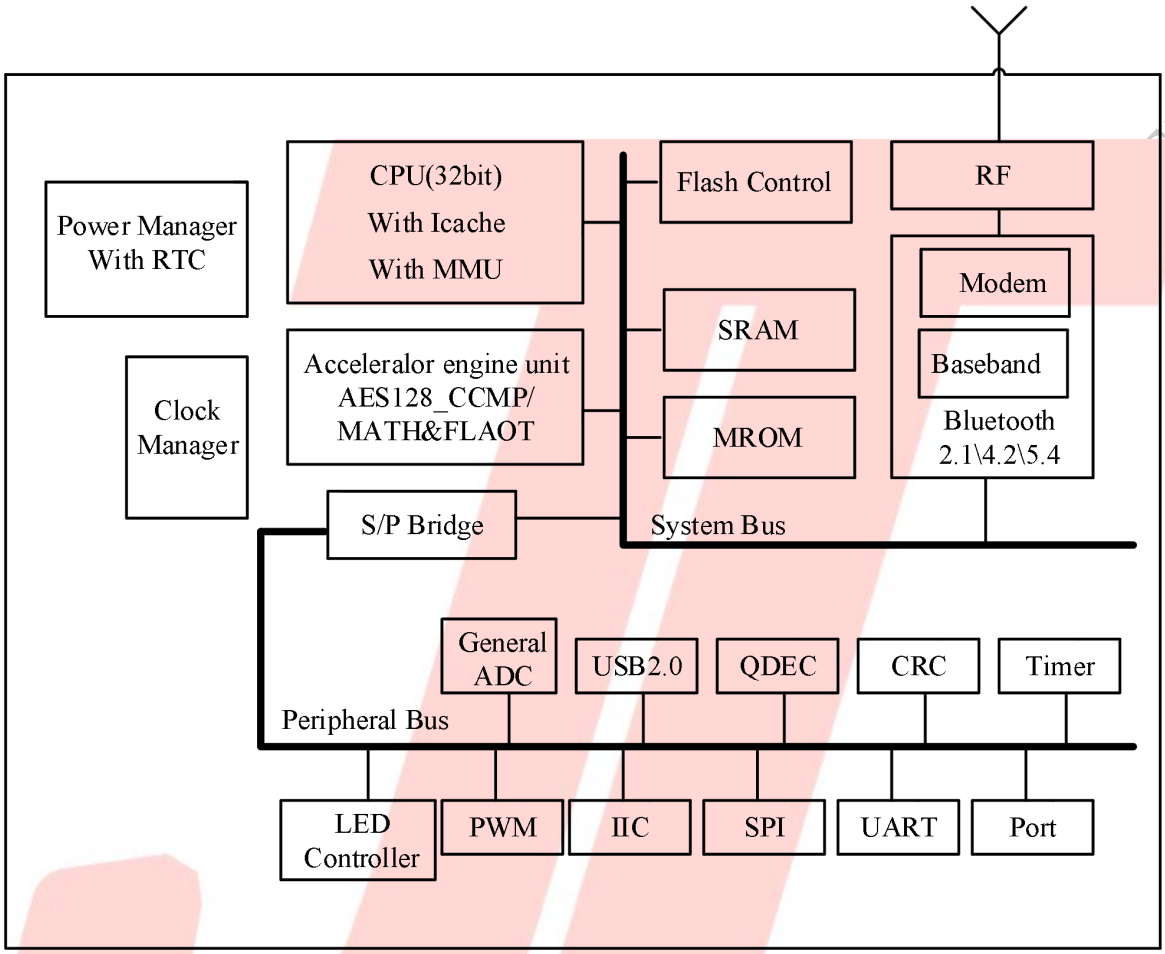


Figure 1-1 AC6328B_SOP8 Block Diagram

2.Pin Definition

2.1 Pin Assignment

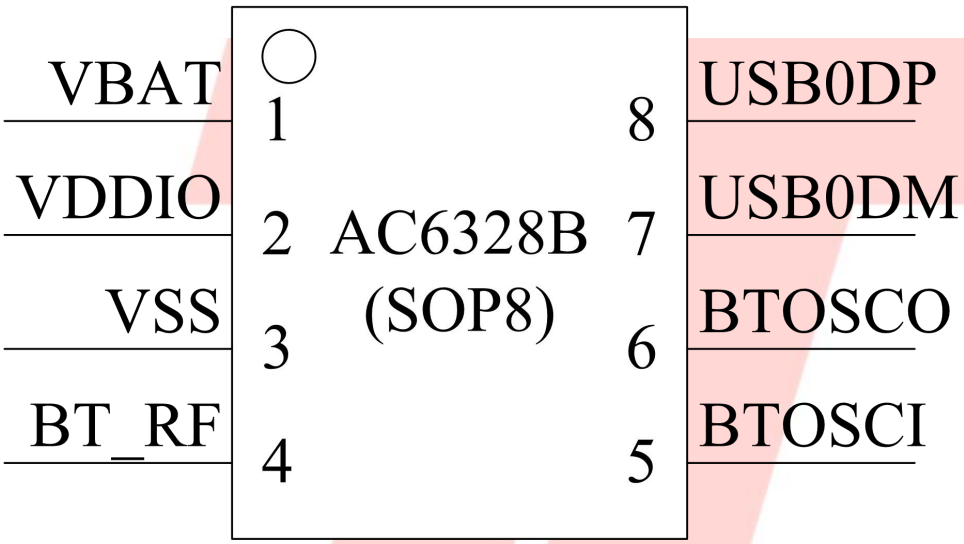


Figure 2-1 AC6328B_SOP8 Package Diagram

2.2 Pin Description

Table 2-1 AC6328B_SOP8 Pin Description

PIN NO.	Name	I/O Type	Function	Other Function
1	VBAT	P	LDO Power	-
2	VDDIO	P	IO Power 3.3V	-
3	VSS	P	GND	-
4	BT_RF	-	RF Antenna	-
5	BTOSCI	I	BTOSCI	-
6	BTOSCO	O	BTOSCO	-
7	USB0DM	I/O	GPIO (pull down)	IIC_SDA_A: IIC SDA(A); ADC11: ADC Channel 11; UART1_RXD: Uart1 Data In(D);
8	USB0DP	I/O	GPIO (pull down)	IIC_SCL_A: IIC SCL(A); ADC10: ADC Channel 10; UART1_TXD: Uart1 Data Out(D);

3.Electrical Characteristics

3.1 Absolute Maximum Ratings

Table 3-1

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-40	+85	℃
Tstg	Storage temperature	-65	+150	℃
VBAT	Supply Voltage	-0.3	5.5	V
V_{VDDIO}	3.3V IO Input Voltage	-0.3	3.6	V

Note : The chip can be damaged by any stress in excess of the absolute maximum ratings listed below

3.2 Recommended Operating Conditions

Table 3-2

Symbol	Parameter	Min	Typ	Max	Unit	Test Conditions
VBAT	Voltage Input	1.8	3.7	5.5	V	_
VDDIO	Voltage Input	-	3.0	-	V	
I_{VDDIO}	Loading current	-	-	60	mA	VBAT = 4.2V

3.3 IO Input/Output Electrical Logical Characteristics

Table 3-3

IO input characteristics						
Symbol	**Parameter**	**Min**	**Typ**	**Max**	**Unit**	**Test Conditions**
V_{IL}	Low-Level Input Voltage	-0.3	_	0.3* VDDIO	V	VDDIO = 3.3V
V_{IH}	High-Level Input Voltage	0.7* VDDIO	_	VDDIO+0.3	V	VDDIO = 3.3V
IO output characteristics						
V_{OL}	Low-Level Output Voltage	_	_	0.33	V	VDDIO = 3.3V
V_{OH}	High-Level Output Voltage	2.7	_	_	V	VDDIO = 3.3V

3.4 Internal Resistor Characteristics

Table 3-4

Port	Drive Strength	Internal Pull-Up Resistor	Internal Pull-Down Resistor	Comment
USB0DP	4mA	1.5K	15K	1. USB0DM&USB0DP default pull down 2. Internal pull-up/pull-down resistance | accuracy ±20%
USB0DM	4mA	180K	15K	

3.5 BT Characteristics

3.5.1 Transmitter

Basic Rate Table 3-5

Parameter		Min	Typ	Max	Unit	Test Conditions
RF Transmit Power		-	4	6	dBm	25℃, Power Supply VBAT=3.7V 2441MHz DH5
RF Power Control Range		-	20	-	dB	
20dB Bandwidth		-	950	-	KHz	
In-band spurious Emissions (BQB Test Mode RF_Tx Power=4dBm)	$F=F_0\pm1MHz$	-	-20	-	dBm	
	$F=F_0\pm2MHz$	-	-45	-	dBm	
	$F=F_0\pm3MHz$	-	-35	-	dBm	
	$F=F_0\pm>3MHz$	-	-40	-	dBm	

Enhanced Data Rate Table 3-6

Parameter		Min	Typ	Max	Unit	Test Conditions
Relative Power		-	-1	-	dB	25℃, Power Supply VBAT=3.7V 2441MHz 2DH5
π/4 DQPSK Modulation Accuracy	DEVM RMS	-	4	-	%	
	DEVM 99%	-	12	-	%	
	DEVM Peak	-	9	-	%	
In-band spurious Emissions (BQB Test Mode RF_Tx Power=4dBm)	$F=F_0\pm1MHz$	-	-4	-	dBm	
	$F=F_0\pm2MHz$	-	-30	-	dBm	
	$F=F_0\pm3MHz$	-	-30	-	dBm	
	$F=F_0\pm>3MHz$	-	-37	-	dBm	

3.5.2 Receiver

Basic Rate **Table 3-7**

Parameter		Min	Typ	Max	Unit	Test Conditions
Sensitivity		-	-91	-	dBm	25℃, Power Supply VBAT=3.7V 2441MHz DH5
Co-channel Interference Rejection		-	6	-	dB	
Adjacent Channel selectivity C/I	+1MHz	-	-7	-	dB	
	-1MHz	-	-7	-	dB	
	+2MHz	-	-37	-	dB	
	-2MHz	-	-39	-	dB	
	+3MHz	-	-32	-	dB	
	-3MHz	-	-43	-	dB	

Enhanced Data Rate **Table 3-8**

Parameter		Min	Typ	Max	Unit	Test Conditions
Sensitivity		-	-93	-	dBm	25℃, Power Supply VBAT=3.7V 2441MHz 2DH5
Co-channel Interference Rejection		-	8	-	dB	
Adjacent Channel selectivity C/I	+1MHz	-	-14	-	dB	
	-1MHz	-	-15	-	dB	
	+2MHz	-	-36	-	dB	
	-2MHz	-	-39	-	dB	
	+3MHz	-	-29	-	dB	
	-3MHz	-	-43	-	dB	

3.5.3 BLE

1M Data Rate **Table 3-9**

Parameter		Min	Typ	Max	Unit	Test Conditions
Sensitivity		-	-95	-	dBm	25℃ Power Supply VBAT=3.7V 2440MHz
RF Transmit Power		-	6.5	8	dBm	
In-band Spurious Emission	|M-N|=2MHz	-	-35	-	dBm	
	|M-N|≥3MHz	-	-33	-	dBm	
Modulation Characteristics	Δf1 avg	-	250	-	KHz	
	Δf2 99%	-	210	-	KHz	
	Δf1avg/Δf2avg	-	0.9	-	/	
Carrier Frequency Offset		-15	-	+15	KHz	
Frequency Drift		-25	-	+25	KHz	
Frequency Drift Rate		-5	-	+5	KHz/50us	

2M Data Rate **Table 3-10**

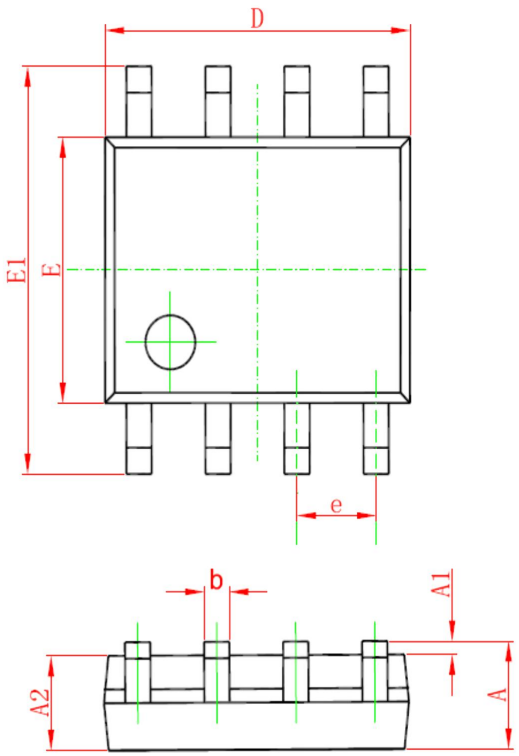
Parameter		Min	Typ	Max	Unit	Test Conditions
Sensitivity		-	-92	-	dBm	25℃ Power Supply VBAT=3.7V 2440MHz
RF Transmit Power		-	6.5	8	dBm	
In-band Spurious Emission	|M-N|=4MHz	-	-40	-	dBm	
	|M-N|=5MHz	-	-40	-	dBm	
	|M-N|≥6MHz	-	-40	-	dBm	
Modulation Characteristics	Δf1 avg	-	500	-	KHz	
	Δf2 99%	-	430	-	KHz	
	Δf1avg/Δf2avg	-	0.9	-	/	
Carrier Frequency Offset		-20	-	+20	KHz	
Frequency Drift		-25	-	+25	KHz	
Frequency Drift Rate		-5	-	+5	KHz/50us	

Long Range **Table 3-11**

Parameter	Min	Typ	Max	Unit	Test Conditions
Sensitivity LE 125K(S8)	-	-102	-	dBm	VBAT=3.7V,25℃ 2440MHz
Sensitivity LE 500K(S2)	-	-99	-	dBm	

4. Package Information

4.1 SOP8(4.9mm*3.9mm)



Symbol	Dimension In Millimeters		Dimension In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	4.700	5.100	0.185	0.201
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.27TYP		0.050TYP	
L	0.400	1.270	0.016	0.050
θ	0^0	8^0	0^0	8^0

Figure 4-1 AC6328B_SOP8 Package

5.Package Type Specification

①Represents different packages

②Represents different memory sizes

2: 2Mbit Flash

4: 4Mbit Flash

6.Revision History

Date	Revision	Description
2021.05.19	V1.0	Initial Release
2022.07.19	V1.1	Update Bluetooth Feature
2023.11.28	V1.2	Add BLE parameter
2023.12.13	V1.3	Update Bluetooth Feature